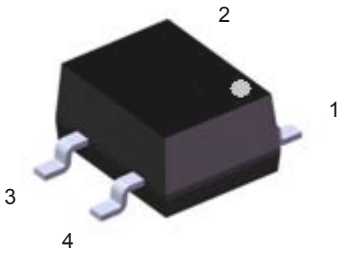
DATASHEET

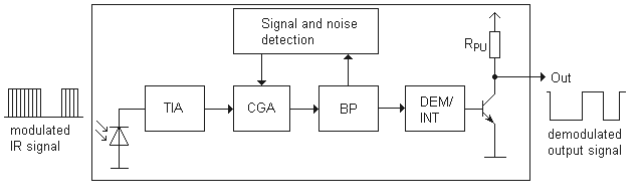
Infrared Receiver Module
IRM-H9XXT/TR2 Series



Pin Configuration

1. GND
2. GND
3. OUT
4. Vcc

Block Diagram



Features

- High protection ability against EMI
- Circular lens for improved reception characteristics
- Available for various carrier frequencies
- Min burst length: 12 cycles
- Min gap length: 16 cycles
- Low operating voltage and low power consumption
- High immunity against ambient light
- Long reception range
- High sensitivity
- Pb free and RoHS compliant

Descriptions

The device is miniature SMD type infrared receiver that has been developed and designed by utilizing the latest IC technology.

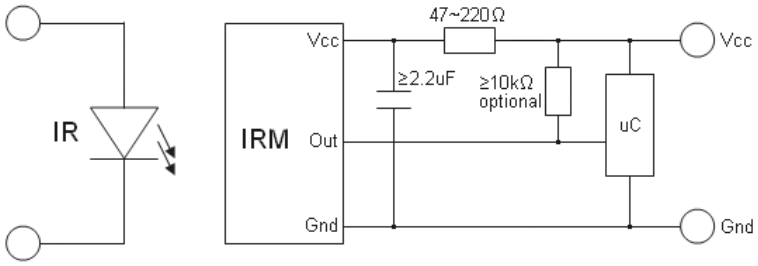
The PIN diode and preamplifier are assembled onto a lead frame and molded into an epoxy package which operates as an IR filter.

The demodulated output signal can directly be decoded by a microprocessor

Applications

- Light detecting portion of remote control
- AV instruments such as Audio, TV, VCR, CD, MD, etc
- Home appliances such as Air-conditioner, Fan, etc
- Other devices using IR remote control
- CATV set top boxes
- Multi-media Equipment

Application Circuit



RC Filter should be connected closely between Vcc pin and GND pin.

Parts Table

Model No.	Carrier Frequency
IRM-H936T/TR2	36 kHz
IRM-H938T/TR2	38 kHz
IRM-H940T/TR2	40 kHz

Absolute Maximum Ratings (T_a=25°C) *1

Parameter	Symbol	Rating	Unit
Supply Voltage	Vs	6	V
Operating Temperature	Topr	-20 ~ +80	°C
Storage Temperature	Tstg	-40 ~ +85	°C
Soldering Temperature *2	Tsol	260	°C

*1 Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
*2 Soldering time≦5 seconds

Electro-Optical Characteristics (Ta=25°C and Vcc=3V)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit	Condition
Current Consumption	Icc	---	0.4	0.7	mA	No input signal
Supply Voltage	Vcc	2.7	---	5.5	V	
Peak Wavelength	λ_p	---	940	---	nm	
Reception Distance	L_0	8	---	---	m	See chapter 'Test method' *3
	L_{45}	5	---	---		
Half Angle (Horizontal)	Θ_h	---	±45	---	deg	
Half Angle (Vertical)	Θ_v	---	±45	---	deg	
High Level Pulse Width	T_{WH}	400	---	800	μs	Test signal according to figure 1 *4
Low Level Pulse Width	T_{WL}	400	---	800	μs	
High Level Output Voltage	V_H	Vcc-0.4	---	---	V	I_{SOURCE}≦1μA
Low Level Output Voltage	V_L	---	0.2	0.5	V	I_{SINK}≦2mA

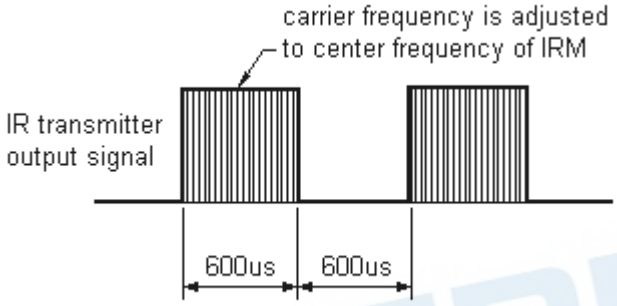
*3 The ray receiving surface at a vertex and relation to the ray axis in the range of θ=0° and θ=45°.
*4 A range from 30cm to the arrival distance. Average value of 50 pulses.

Test Method

The specified electro-optical characteristic is satisfied under the following Conditions:

1. Measurement environment
   A place without extreme light reflected
2. External light
   Ordinary white fluorescent lamps (Light source temperature 2856°K, Ee≦10Lux) without high frequency modulation
3. Standard transmitter
   The test transmitter is calibrated by using the circuit shown in figure 2. The radiation intensity of the transmitter is adjusted until **Vo=400mVp-p.** Both, the test transmitter and the photo diode, have a peak wavelength of 940nm. The photo diode for calibration is PD438B (λp=940nm, Vr=5V).
4. Measuring system According to the measuring system shown in Fig.-3

Fig.-1 Transmitter Wave Form



D.U.T output Pulse

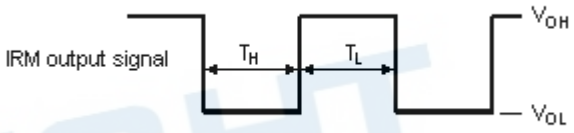


Fig.-2 Measuring Method

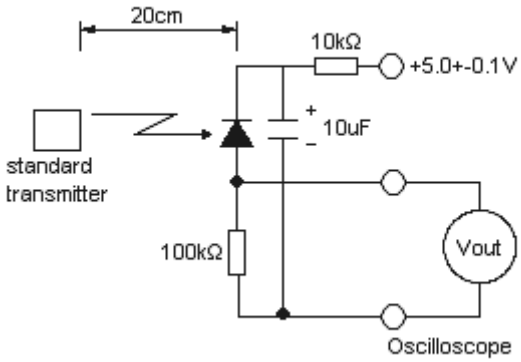
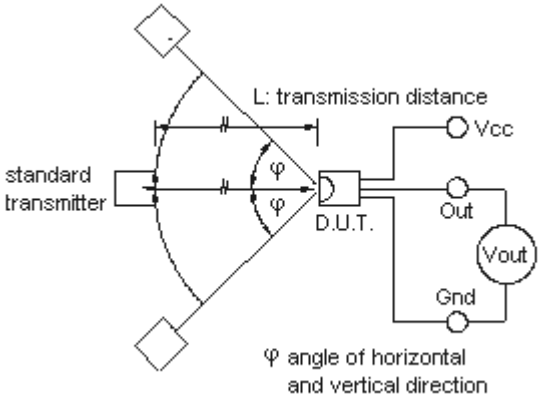


Fig.-3 Measuring System



Typical Performance Curves

Fig.4 Relative Responsibility vs. Wavelength

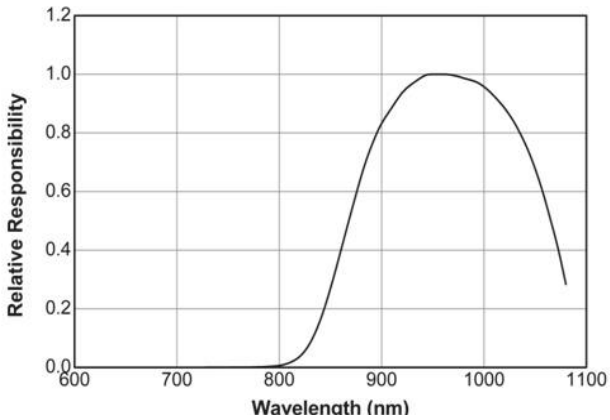


Fig.-5 Relative Sensitivity vs. Horizontal Angle

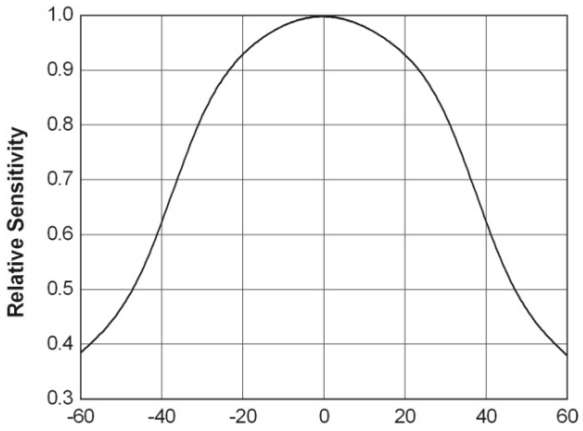


Fig.-6 Output Pulse Width vs. Transmission Distance

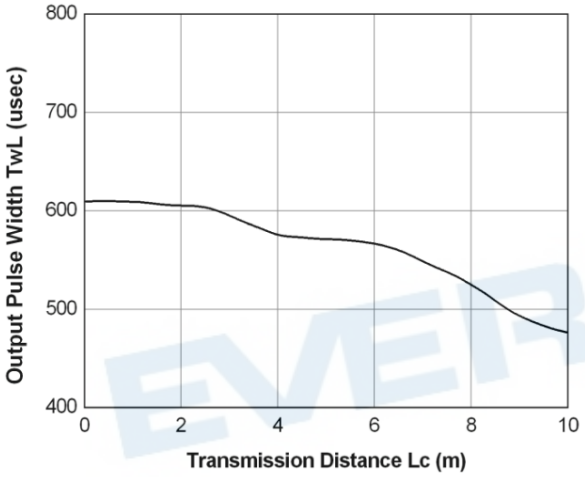


Fig.-7 Relative Transmission Distance vs. Supply Voltage

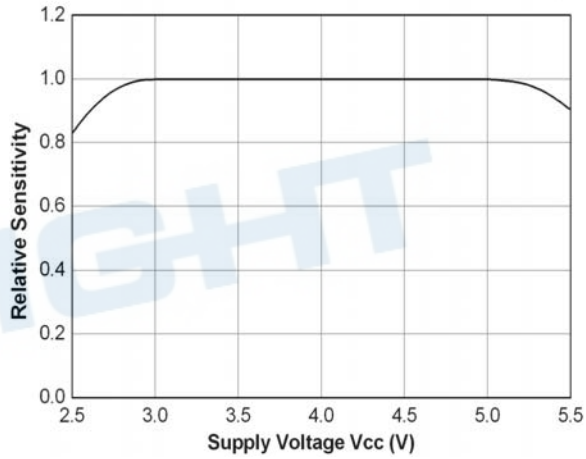
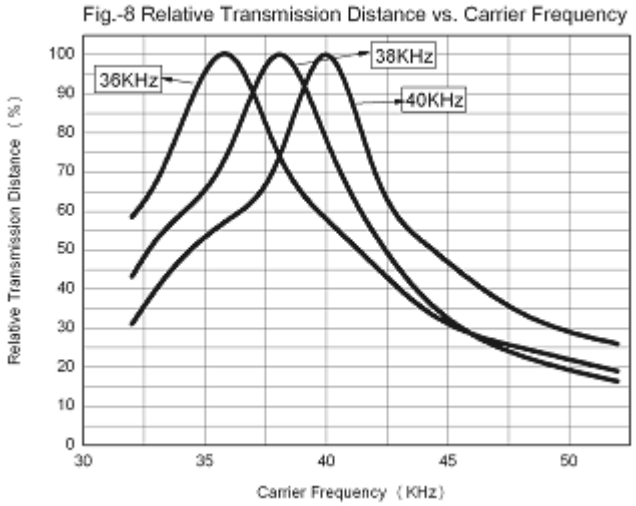
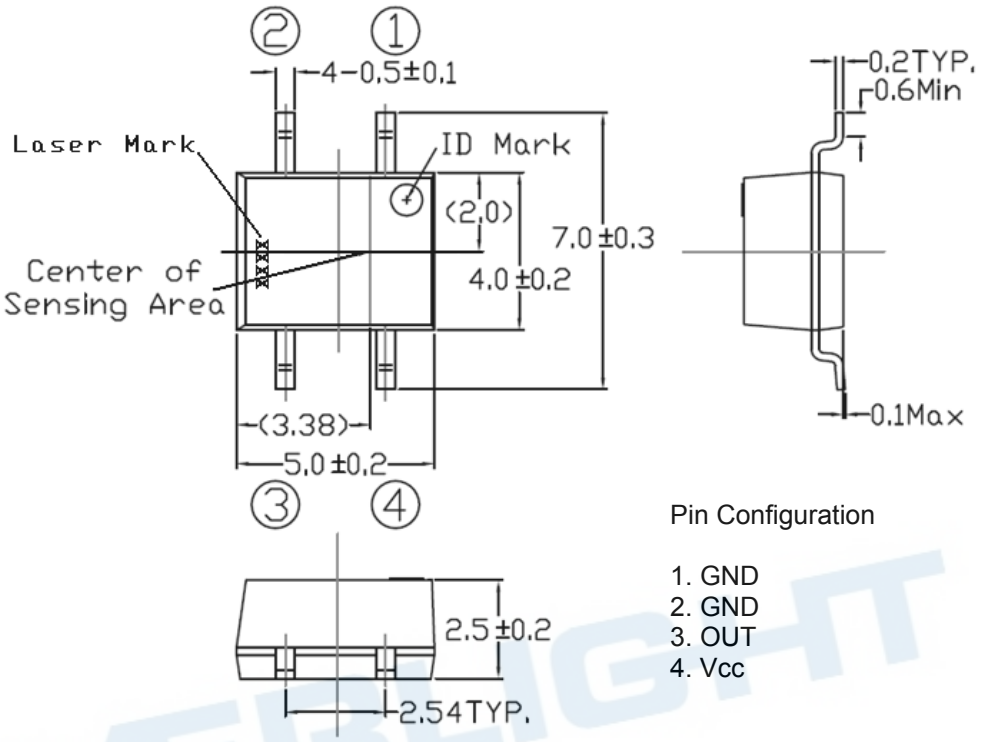


Fig.-8 Relative Transmission Distance vs. Carrier Frequency



Package Dimenstions

(Dimensions in mm)



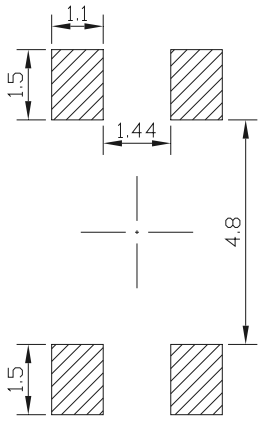
Pin Configuration

1. GND
2. GND
3. OUT
4. Vcc

Note: Tolerances unless otherwise mentioned ±0.5mm.

Recommend soldering patterns

The following soldering patterns are recommended for reflow-soldering



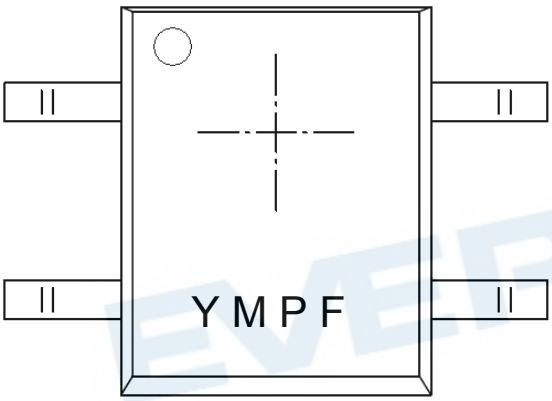
Notice: Suggested pad dimension is just for reference only.
Please modify the pad dimension based on individual need.

Code information

Protocol	Suitable	Protocol	Suitable
Matsushita	Yes	Sony 12 bit	Yes
NEC	Yes	Sony 15 bit	No
RC5	Yes	Sony 20 bit	No
RC6[1)]	Yes	Sharp	Yes
Toshiba	Yes	Zenith	Yes
RCA	No	Continuous Code	No

1) RC6 is only compatible if the data low time is 25ms or more.

Device Marking



Notes

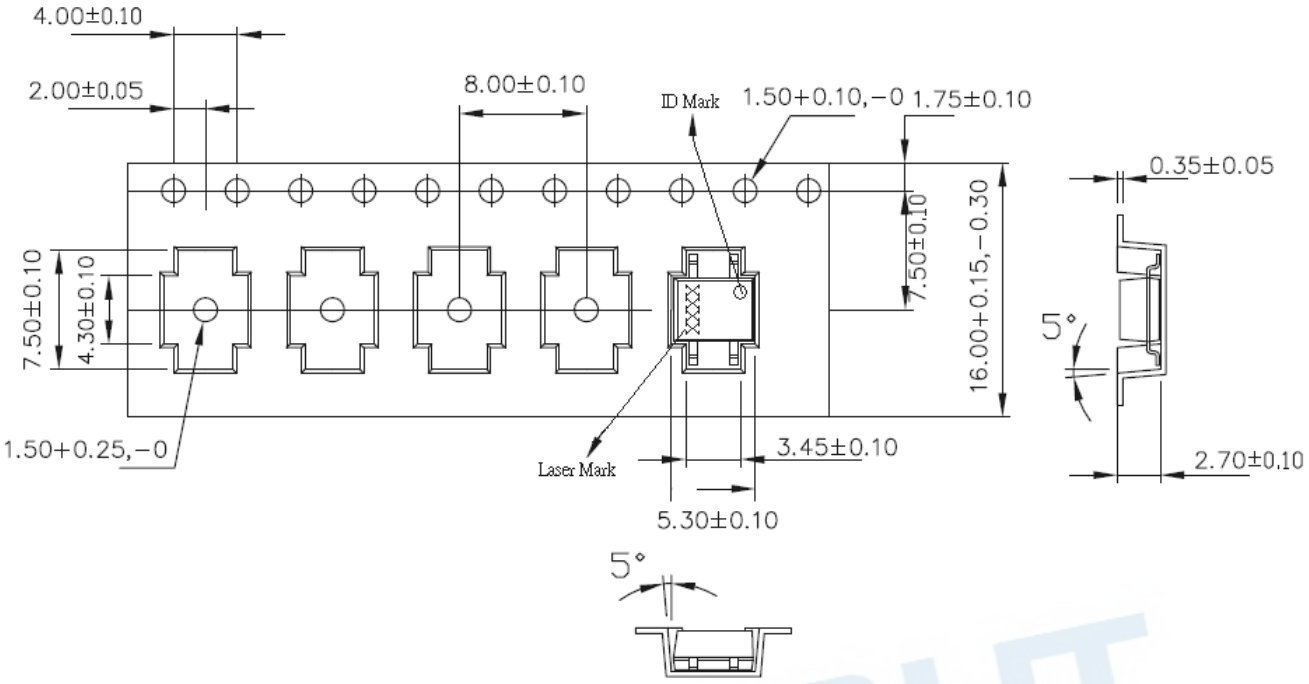
Y denotes Years code

M denotes Month code

P denotes Device number

F denotes Carrier frequency

Tape & Reel Packing Specifications



Packing Quantity

2000 pcs / Reel

5 Reels / Carton

Recommended method of storage

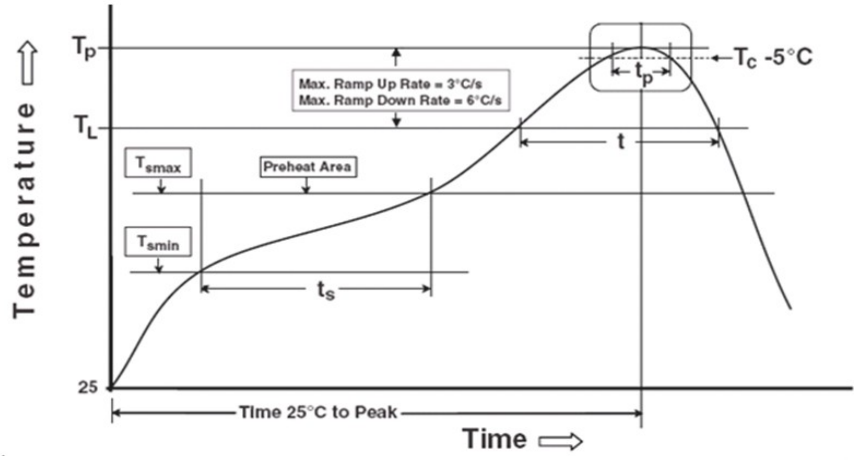
The following are general recommendations for moisture sensitive level (MSL) 4 storage and use:

1. Shelf life in sealed bag from the bag seal date: 12 months at 10℃~30℃ and < 90% relative humidity (RH)
2. After bag is opened, devices that will be subjected to reflow solder or other high temperature process must mounted within 72 hours of factory conditions at 10°C~30°C and 60%RH.
3. If the moisture absorbent material (silica gel) has faded away or the IRM has exceeded the storage time. Baking treatment is required, refer to IPC/JEDEC J-STD-033 for bake procedure or recommend the conditions: 96 hours at 60°C ± 5°C and < 5 % RH.

ESD Precaution

Proper storage and handing procedures should be followed to prevent ESD damage to the devices especially when they are removed from the Anti-static bag. Electro-Static Sensitive Devices warning labels are on the packing.

Solder Reflow Temperature Profile



Note: Reference: IPC/JEDEC J-STD-020D

Preheat	
Temperature min (T_{smin})	150 °C
Temperature max (T_{smax})	200°C
Time (T_{smin} to T_{smax}) (t_s)	60-120 seconds
Average ramp-up rate (T_{smax} to T_p)	3 °C/second max
Other	
Liquidus Temperature (T_L)	217 °C
Time above Liquidus Temperature (t_L)	60-150 sec
Peak Temperature (T_P)	260°C
Time within 5 °C of Actual Peak Temperature: T_P - 5°C	30 s
Ramp- Down Rate from Peak Temperature	6°C /second max.
Time 25°C to peak temperature	8 minutes max.
Reflow times	2 times

Note:

1. Suggest that reflow soldering should not be done more than two times.
2. When soldering, do not put stress on the IRM device during heating.
3. After soldering, do not warp the circuit board.

DISCLAIMER

1. EVERLIGHT reserves the right(s) on the adjustment of product material mix for the specification.
2. The product meets EVERLIGHT published specification for a period of twelve (12) months from date of shipment.
3. The graphs shown in this datasheet are representing typical data only and do not show guaranteed values.
4. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from the use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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